

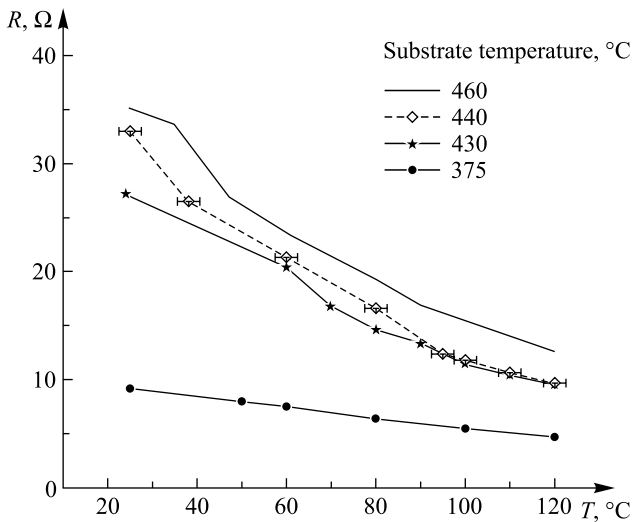


Fig. 3. Temperature dependence of resistance (R)

of the InSb films on semi-insulating GaAs(100) substrates deposited by explosive thermal evaporation at different substrate temperatures